ESDL2011

ESD Protection Diode

Micro-Packaged Diodes for ESD Protection

The ESDL2011 is designed to protect voltage sensitive components that require low capacitance from ESD and transient voltage events. Excellent clamping capability, low capacitance, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its low capacitance, the part is well suited for use in high speed data line applications.

Features

- Low Capacitance 0.17 pF (Typ)
- Low Clamping Voltage
- Small Body Outline Dimensions: 0.60 mm x 0.30 mm
- Low Body Height: 0.2 mm
- Stand-off Voltage: 1.0 V
- IEC61000-4-2 Level 4 ESD Protection
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- USB 3.x
- Thunderbolt 3.0

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Contact Air		±15 ±15	kV
Total Power Dissipation on FR-4 Board (Note 1) @ T _A = 25°C Thermal Resistance, Junction-to-Ambient	P _D R _{θJA}	313 400	mW °C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. $FR-4 = 28 \text{ mm}^2 \text{ 1 oz. Cu JEDEC JESD51} - 3 \text{ two layer PCB.}$



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DSN2 (Side wall isolated) CASE 152AX





A = Specific Device Code

ORDERING INFORMATION

Device	Package	Shipping [†]
ESDL2011PFCT5G	DSN2 (Pb-Free)	10000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

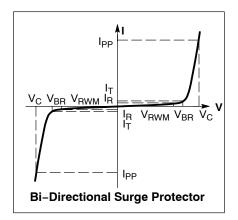
1

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Parameter
Ipp	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ IPP
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current

^{*}See Application Note AND8308/D for detailed explanations of datasheet parameters.



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	I/O Pin to GND			1.0	V
Breakdown Voltage	V_{BR}	I _T = 1 mA, I/O Pin to GND	1.4	1.65	2.3	V
Reverse Leakage Current	I _R	V _{RWM} = 1.0 V		30	500	nA
Clamping Voltage (Note 2)	V _C	IEC61000-4-2, ±8 kV Contact	Fi	gures 1 and	2	V
Clamping Voltage 200 ns TLP	V _C	IPP = 4 A IEC61000-4-2 Level 1 Equivalent (±2 kV Contact, ±4 kV Air)		3.5	4.0	V
		Ipp = 8 A $\begin{cases} IEC61000-4-2 \text{ Level 2 Equivalent} \\ (\pm 4 \text{ kV Contact}, \pm 8 \text{ kV Air}) \end{cases}$		4.8	6.0	
Reverse Peak Pulse Current per Figure 12	Ірр	per IEC61000-4-5 (1.2/50 μ s), R _{eq} = 12 Ω	3.5	4.5		Α
Clamping Voltage 1.2/50 μs Waveform per Figure 12	V _C	I_{PP} = 2.1 A, IEC61000–4–5 (1.2/50 μs), R_{eq} = 12 Ω		2.9	3.5	٧
Clamping Voltage 1.2/50 μs Waveform per Figure 12	V _C	I_{PP} = 3.5 A, IEC61000–4–5 (1.2/50 μs), R_{eq} = 12 Ω		3.6	4.0	V
Dynamic Resistance (TLP)	R_{DYN}	I/O Pin to GND (4 A to 8 A, 200 ns TLP)		0.34	0.5	Ω
Junction Capacitance	CJ	V _R = 0 V, f = 1 MHz		0.17	0.20	pF
Insertion Loss	ΙL	f = 5 GHz f = 10 GHz		0.165 0.34	0.20 0.40	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 2. For test procedure see application note AND8307/D.
- 3. ANSI/ESD STM5.5.1 Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model. TLP conditions: $Z_0 = 50 \Omega$, $t_p = 200$ ns, $t_r = 4$ ns, averaging window; $t_1 = 170$ ns to $t_2 = 190$ ns.

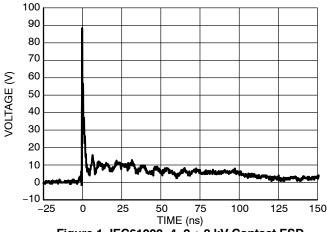


Figure 1. IEC61000-4-2 + 8 kV Contact ESD Clamping Voltage

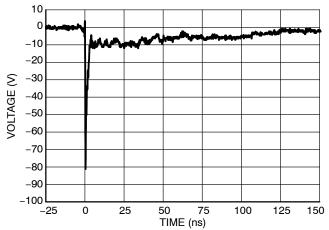


Figure 2. IEC61000-4-2 - 8 kV Contact ESD Clamping Voltage

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TYPICAL CHARACTERISTICS

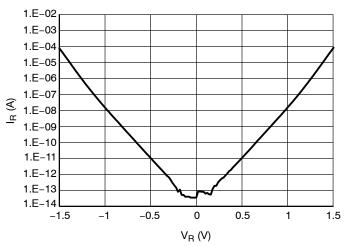


Figure 3. IV Characteristics

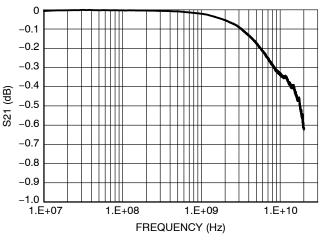


Figure 4. Insertion Loss

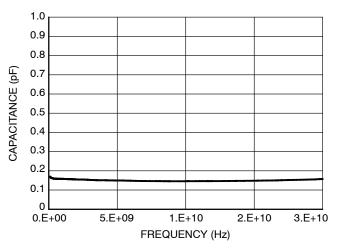


Figure 5. Typical Capacitance over Frequency

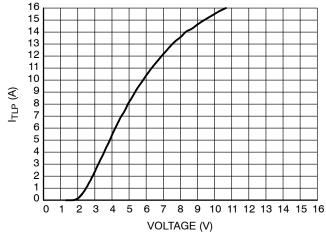


Figure 6. Positive 200 ns TLP IV Curve

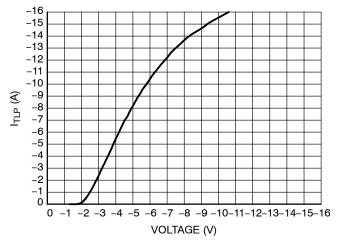


Figure 7. Negative 200 ns TLP IV Curve

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TYPICAL CHARACTERISTICS

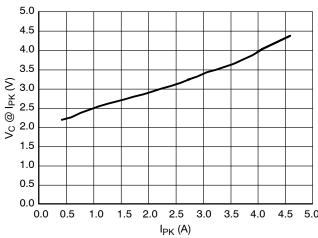


Figure 8. Positive Clamping Voltage vs. Peak Pulse Current (per IEC61000–4–5 (t $_p$ = 1.2/50 $\mu s,~R_{eq}$ = 12 $\Omega))$

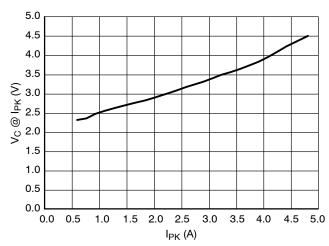


Figure 9. Negative Clamping Voltage vs. Peak Pulse Current (per IEC61000–4–5 (t $_p$ = 1.2/50 $\mu s,~R_{eq}$ = 12 $\Omega))$

IEC 61000-4-2 Spec.

Level	Test Volt- age (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

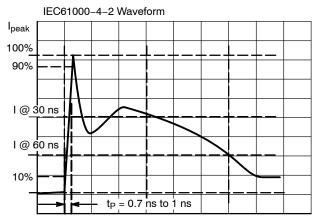


Figure 10. IEC61000-4-2 Spec

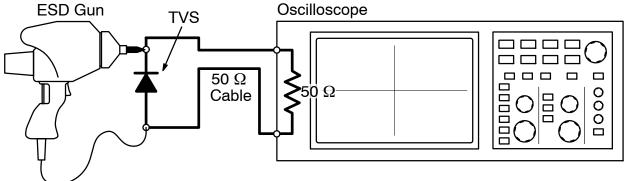


Figure 11. Diagram of ESD Test Setup

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage

at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.

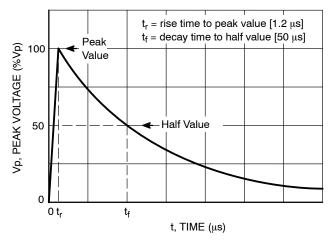
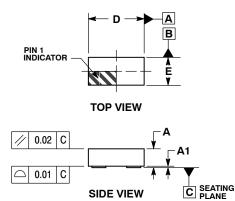


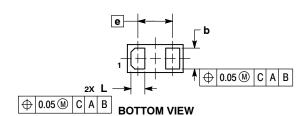
Figure 12. IEC61000-4-5 1.2/50 μs Pulse Waveform



X4DFN2, 0.60x0.30, 0.36P CASE 152AX **ISSUE G**

DATE 12 APR 2019





NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.175	0.200	0.225	
A1	0.018 REF			
b	0.205	0.215	0.225	
D	0.575	0.600	0.625	
Е	0.275	0.300	0.325	
е	0.36 BSC			
L	0.145	0.155	0.165	

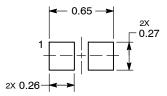
GENERIC MARKING DIAGRAM*



X = Specific Device Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present. Some products may not follow the Generic Marking.

RECOMMENDED SOLDER FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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